

High voltage power Schottky rectifier

Features

- high junction temperature capability
- good trade-off between leakage
- current and forward voltage drop
- low leakage current
- insulated package: TO-220FPAB
 - insulating voltage = 2000 V DC
 - capacitance = 45 pF
- avalanche capability specified

Description

Dual center tap Schottky rectifier designed for high frequency switched mode power supplies.

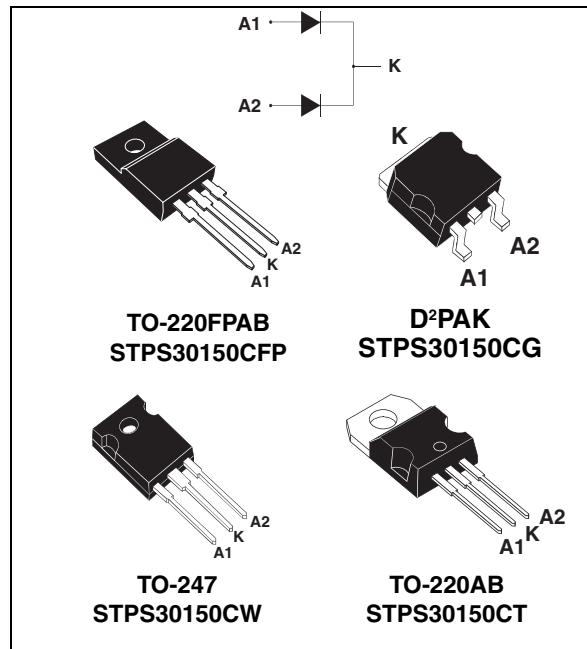


Table 1. Device summary

$I_{F(AV)}$	2 x 15 A
V_{RRM}	150 V
T_j (max)	175 °C
V_F (max)	0.75 V

1 Characteristics

Table 2. Absolute ratings (limiting values, per diode)

Symbol	Parameter				Value	Unit
V_{RRM}	Repetitive peak reverse voltage				150	V
$I_{F(RMS)}$	Forward rms current				30	A
$I_{F(AV)}$	Average forward current $\delta = 0.5$	TO-220FPAB	$T_c = 120^\circ\text{C}$	Per diode	15	A
		TO-220AB TO-247/D ² PAK	$T_c = 155^\circ\text{C}$	Per device	30	
I_{FSM}	Surge non repetitive forward current		$t_p = 10 \text{ ms sinusoidal}$		220	A
P_{ARM}	Repetitive peak avalanche power		$t_p = 1 \mu\text{s}$	$T_j = 25^\circ\text{C}$	10500	W
T_{stg}	Storage temperature range				-65 to + 175	$^\circ\text{C}$
T_j	Maximum operating junction temperature ⁽¹⁾				175	$^\circ\text{C}$
dV/dt	Critical rate of rise of reverse voltage				10000	V/ μs

1. $\frac{dP_{tot}}{dT_j} < \frac{1}{R_{th(j-a)}}$ condition to avoid thermal runaway for a diode on its own heatsink

Table 3. Thermal resistances

Symbol	Parameter			Value	Unit	
$R_{th(j-c)}$	Junction to case	TO-220FPAB	Per diode	4	$^\circ\text{C/W}$	
			Total	3.3		
		TO-220AB/D ² PAK	Per diode	1.6		
			Total	0.85		
$R_{th(c)}$	Coupling	TO-247	Per diode	1.5	$^\circ\text{C/W}$	
			Total	0.8		
		TO-220FPAB			2.6	
		TO-220AB/D ² PAK/TO-247			0.1	

When the diodes 1 and 2 are used simultaneously :

$$\Delta T_j(\text{diode 1}) = P(\text{diode 1}) \times R_{th(j-c)}(\text{Per diode}) + P(\text{diode 2}) \times R_{th(c)}$$

Table 4. Static electrical characteristics (per diode)

Symbol	Parameter	Test conditions		Min.	Typ.	Max.	Unit
$I_R^{(1)}$	Reverse leakage current	$T_j = 25^\circ\text{C}$	$V_R = V_{RRM}$			6.5	μA
		$T_j = 125^\circ\text{C}$				8	mA
$V_F^{(2)}$	Forward voltage drop	$T_j = 25^\circ\text{C}$	$I_F = 15 \text{ A}$			0.92	V
		$T_j = 125^\circ\text{C}$	$I_F = 15 \text{ A}$			0.69	
		$T_j = 25^\circ\text{C}$	$I_F = 30 \text{ A}$			1	
		$T_j = 125^\circ\text{C}$	$I_F = 30 \text{ A}$			0.8	

1. Pulse test: $t_p = 5\text{ms}$, $\delta < 2\%$ 2. Pulse test: $t_p = 380 \mu\text{s}$, $\delta < 2\%$

To evaluate the conduction losses use the following equation:

$$P = 0.64 \times I_{F(AV)} + 0.0073 I_F^2 (\text{RMS})$$

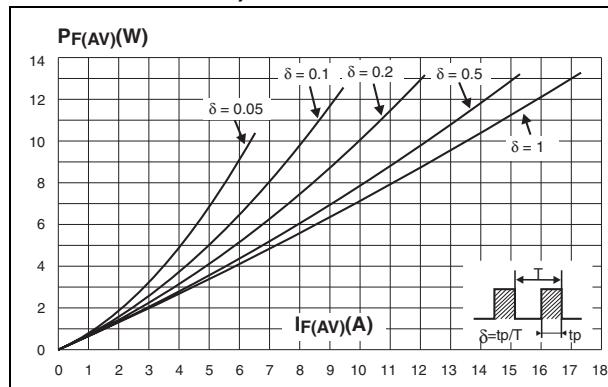
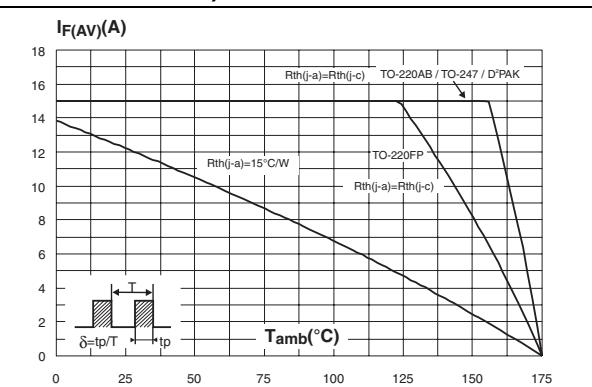
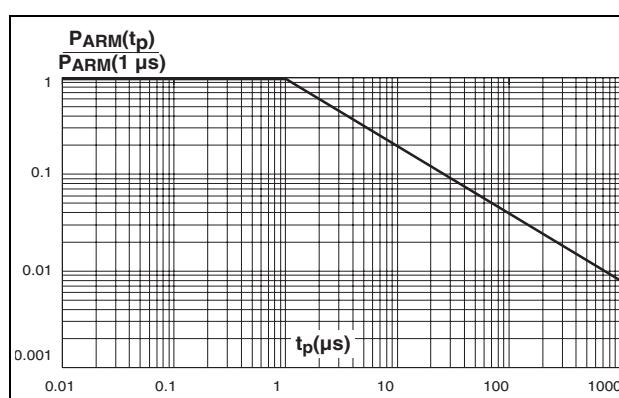
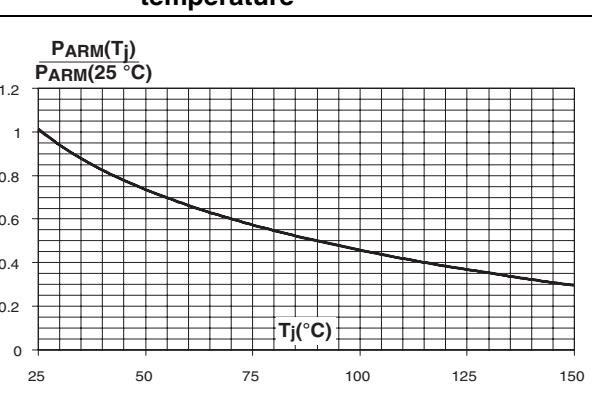
Figure 1. Average forward power dissipation versus average forward current (per diode)**Figure 2. Average forward current versus ambient temperature ($\delta = 0.5$, per diode)****Figure 3. Normalized avalanche power derating versus pulse duration****Figure 4. Normalized avalanche power derating versus junction temperature**

Figure 5. Non repetitive surge peak forward current vs. overload duration (max. values, per diode)

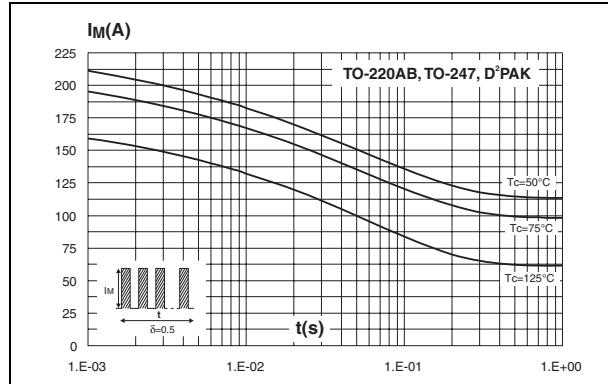


Figure 7. Variation of thermal impedance junction to case versus pulse duration (per diode)

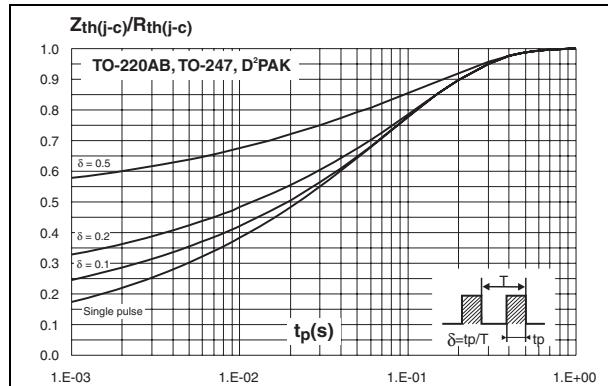


Figure 9. Reverse leakage current versus reverse voltage applied (typical values, per diode)

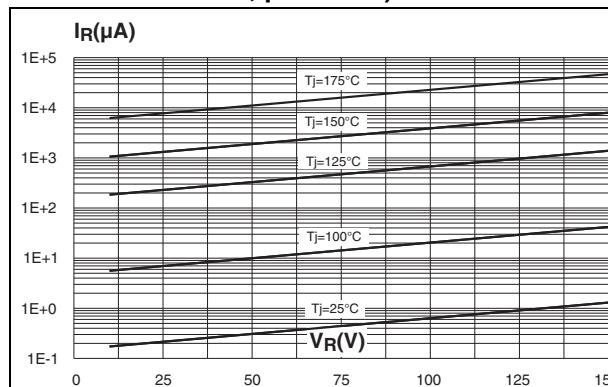


Figure 6. Non repetitive surge peak forward current vs. overload duration (max. values, per diode) (TO-220FPAB)

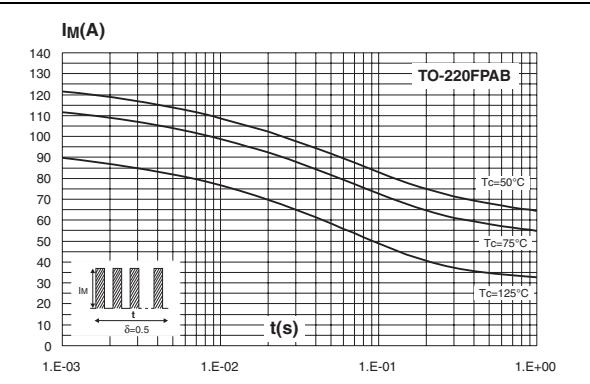


Figure 8. Variation of thermal impedance junction to case versus pulse duration (per diode) (TO-220FPAB)

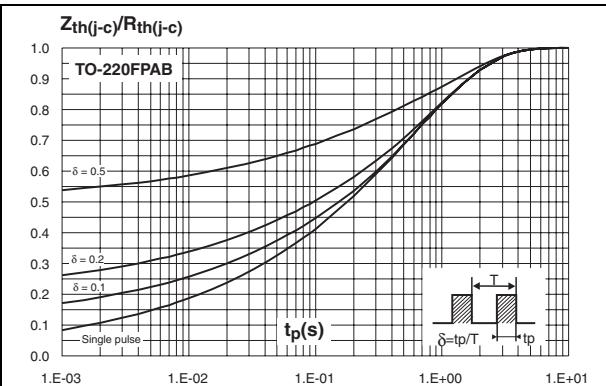


Figure 10. Junction capacitance versus reverse voltage applied (typical values, per diode)

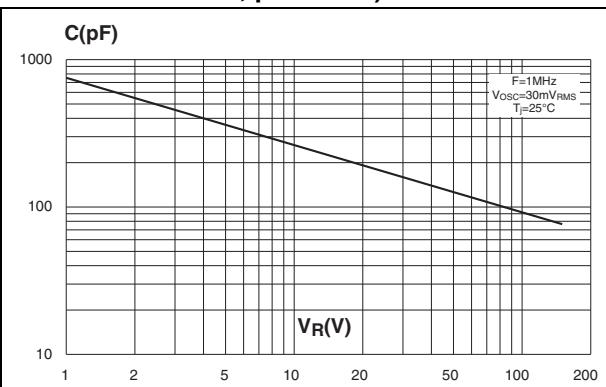


Figure 11. Forward voltage drop versus forward current (maximum values, per diode)

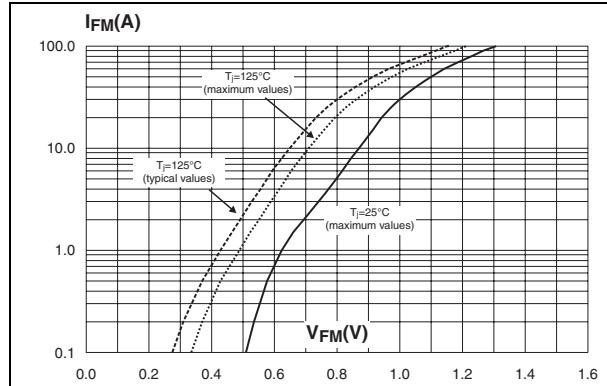
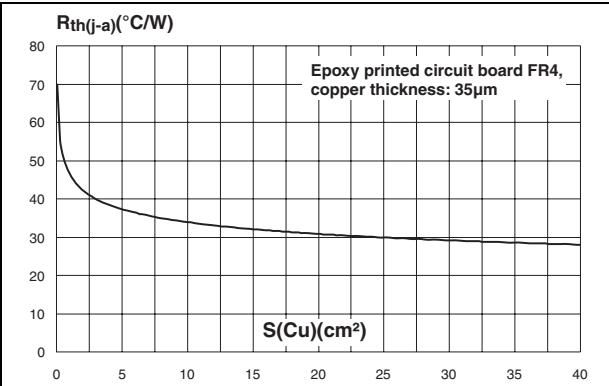


Figure 12. Thermal resistance junction to ambient versus copper surface under tab for D²PAK



2 Package Information

- Epoxy meets UL94, V0
- Cooling method: (C) conduction
- Recommended torque values (TO-220FPAB, TO-220AB: 0.4 to 0.6 N·m
- Torque values (TO-247): 0.55 N·m recommended, 1.0 N·m maximum

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Table 5. TO-220FPAB package dimensions

Ref	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.4	4.6	0.173	0.181
B	2.5	2.7	0.098	0.106
D	2.5	2.75	0.098	0.108
E	0.45	0.70	0.018	0.027
F	0.75	1	0.030	0.039
F1	1.15	1.70	0.045	0.067
F2	1.15	1.70	0.045	0.067
G	4.95	5.20	0.195	0.205
G1	2.4	2.7	0.094	0.106
H	10	10.4	0.393	0.409
L2	16 Typ.		0.63 Typ.	
L3	28.6	30.6	1.126	1.205
L4	9.8	10.6	0.386	0.417
L5	2.9	3.6	0.114	0.142
L6	15.9	16.4	0.626	0.646
L7	9.00	9.30	0.354	0.366
Dia.	3.00	3.20	0.118	0.126

Table 6. D²PAK package dimensions

Ref	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.40	4.60	0.173	0.181
A1	2.49	2.69	0.098	0.106
A2	0.03	0.23	0.001	0.009
B	0.70	0.93	0.027	0.037
B2	1.14	1.70	0.045	0.067
C	0.45	0.60	0.017	0.024
C2	1.23	1.36	0.048	0.054
D	8.95	9.35	0.352	0.368
E	10.00	10.40	0.393	0.409
G	4.88	5.28	0.192	0.208
L	15.00	15.85	0.590	0.624
L2	1.27	1.40	0.050	0.055
L3	1.40	1.75	0.055	0.069
M	2.40	3.20	0.094	0.126
R	0.40 typ.		0.016 typ.	
V2	0°	8°	0°	8°

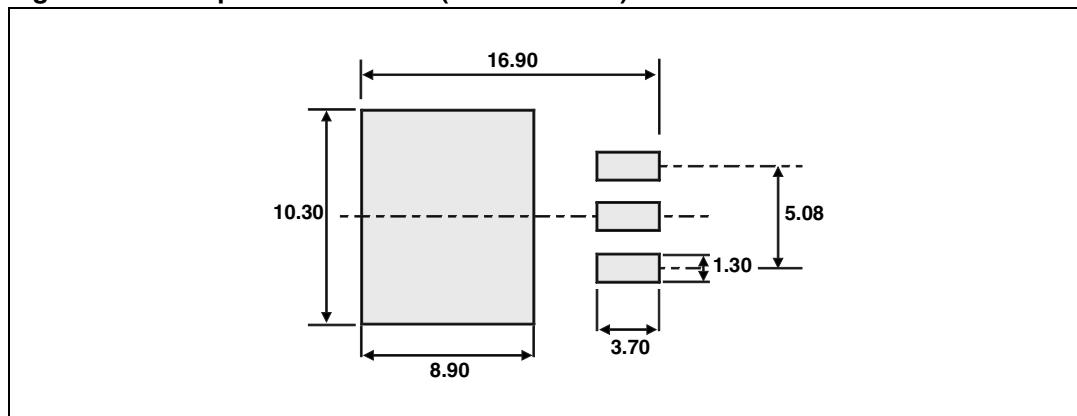
Figure 13. Footprint dimensions (in millimeters)

Table 7. TO-220AB package dimensions

Ref	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.40	4.60	0.173	0.181
C	1.23	1.32	0.048	0.051
D	2.40	2.72	0.094	0.107
E	0.49	0.70	0.019	0.027
F	0.61	0.88	0.024	0.034
F1	1.14	1.70	0.044	0.067
F2	1.14	1.70	0.044	0.067
G	4.95	5.15	0.194	0.202
G1	2.40	2.70	0.094	0.106
H2	10	10.40	0.393	0.409
L2	16.4 typ.		0.645 typ.	
L4	13	14	0.511	0.551
L5	2.65	2.95	0.104	0.116
L6	15.25	15.75	0.600	0.620
L7	6.20	6.60	0.244	0.259
L9	3.50	3.93	0.137	0.154
M	2.6 typ.		0.102 typ.	
Diam.	3.75	3.85	0.147	0.151

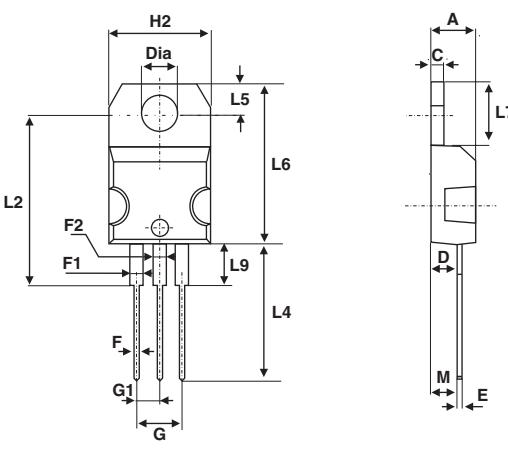
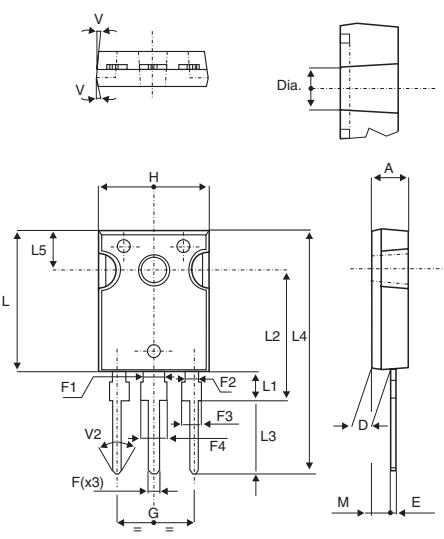


Table 8. TO-247 package dimensions

Ref	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.85		5.15	0.191		0.203
D	2.20		2.60	0.086		0.102
E	0.40		0.80	0.015		0.031
F	1.00		1.40	0.039		0.055
F1		3.00			0.118	
F2		2.00			0.078	
F3	2.00		2.40	0.078		0.094
F4	3.00		3.40	0.118		0.133
G		10.90			0.429	
H	15.45		15.75	0.608		0.620
L	19.85		20.15	0.781		0.793
L1	3.70		4.30	0.145		0.169
L2		18.50			0.728	
L3	14.20		14.80	0.559		0.582
L4		34.60			1.362	
L5		5.50			0.216	
M	2.00		3.00	0.078		0.118
V		5°			5°	
V2		60°			60°	
Dia.	3.55		3.65	0.139		0.143



The technical drawing illustrates the physical dimensions of a TO-247 package. It features a top view showing the overall height (H), lead spacing (L), and lead length (L1-L5). The side view provides details on the lead thickness (F1-F4), lead pitch (G), and body height (D). Other dimensions include the lead diameter (Dia.), lead angle (V), and lead taper angle (V2). The drawing also includes a small cross-sectional view at the bottom left.

3 Ordering Information

Table 9. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STPS30150CT	STPS30150CT	TO-220AB	2 g	50	Tube
STPS30150CFP	STPS30150CFP	TO-220FPAB	1.9 g	50	Tube
STPS30150CW	STPS30150CW	TO-247	4.4 g	30	Tube
STPS30150CG	STPS30150CG	D ² PAK	1.48 g	50	Tube
STPS30150CG-TR	STPS30150CG	D ² PAK	1.48 g	1000	Tape and reel

4 Revision history

Table 10. Document revision history

Date	Revision	Changes
Feb-2004	7	Previous release.
26-Nov-2010	8	Added ECOPACK statement. Corrected package name in Figure 12 .

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